

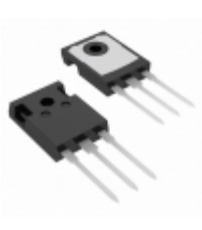
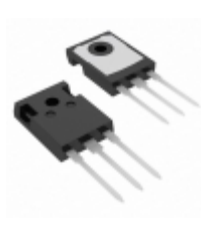
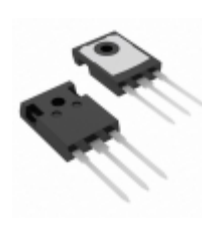


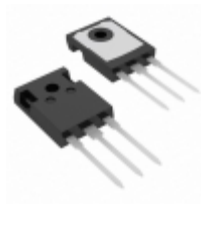
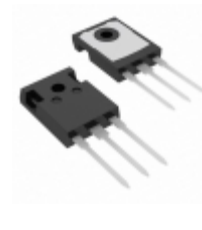
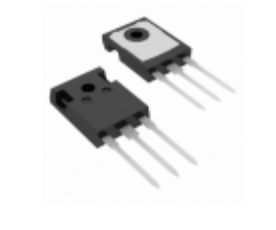
 	<h2 style="color: red;">FQH44N10_F133</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQH44N10_F133</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> FQH44N10_F133 Fairchild/ON Semiconductor</p> <p><b>Datenblätter:</b>  <a href="#">FQH44N10_F133.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 32363 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQH44N10_F133</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	FQH44N10_F133 Fairchild/ON Semiconductor
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Verlustleistung (max)	180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	48A (Tc)
Rds On (Max) @ Id, Vgs	39 mOhm @ 24A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1800pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube

FQH44N10\_F133 ist neu im Original, Suche FQH44N10\_F133 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQH44N10\_F133 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQH44N10\_F133: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQH44N10-F133</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>	 <p><b>FQH70N10</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 70A TO-247</p>	 <p><b>FQH8N100C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 1000V 8A TO-247</p>	 <p><b>FQH70N15</b> FSC FQH70N15 FSC</p>
 <p><b>FQH44N10</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>	 <p><b>FQH18N50V2</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 20A TO-247</p>	 <p><b>FQH18N50V2</b> Fairchild/ON Semiconductor MOSFET N-CH 500V 20A TO-247</p>	 <p><b>FQH44N10</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>

### heiße Teile

Mehr

⊕ 0402YA6R8CAT2A	↔ 08055A820JAT2A	⇒ 6MBP160RU4A060-01	D ADP7102ACPZ-9.0-R7	⇒ AK4182AVN-L
⊖ AP1604ASN	⊕ BM02B-GHS-TBT	D BU8244F-E2	⇒ C1005X7R1V333M050BB	⇒ CCF1N2.5TTE
⊕ D10JDB80V	⊖ DAC7574IDGSR	⊕ DTC115EET1G	↔ ESD5Z5CA	⇒ FDFS2P753Z
D FJZ733GTF	⊕ FQH44N10	⊖ FQH44N10	⊕ FQH70N15	⇒ FQH8N100C
⇒ FQH8N100C	↔ FQPF5N80	⊕ GRM219R72A472KA01J	⊖ IRF821PBF	⇒ IRFK2D350
↔ ISL3232CVZ	⇒ LL4150GS08	D LM80CIMTX-5/NOPB	⊕ LMSZ5240BT1G/1206-10V	⊖ LRCM04RC09T
⊕ LTC3129IUD-1#PBF	D LTC3717EGN#TRPBF	⇒ MAX6129AEUK33+T	↔ MG50S1BS1	⇒ MIC2289-15BML
⊖ NCV33269DTRK-5.0G	⊕ NFM31PC276B0J3L	↔ NL27WZ32US	⇒ OF140SC50D	⇒ PMBT2222A/CU
⊕ RT314005	⊖ RT9261-32CB	⊕ SI4493DY-T1-E3	D SKIIP83AC12IT46	⇒ SKT251/06C
↔ STTH1L06UFY	⊕ TCM811JERCTR	⊖ TK40P03M1	⊕ TLV431AIDBVR	⇒ V24A24H400A

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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